D irect observation of the oxygen isotope e ect on the in-plane magnetic eld penetration depth in optimally doped Y B a_2 C u_3 O $_7$

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We report the rst direct observation of the oxygen-isotope ($^{16}O/^{18}O$) e ect on the in-plane penetration depth _{ab} in a nearly optimally doped YBa₂Cu₃O₇ In using the novel low-energy muon-spin rotation technique. Spin polarized low energy muons are implanted in the lm at a known depth z beneath the surface and precess in the localm agnetic eld B (z). This feature allows us to measure directly the prole B (z) of the magnetic eld inside the superconducting lm in the M eissner state and to make a model independent determination of _{ab}. A substantial isotope shift

 $a_{b} = a_{b} = 2.3(7)$ % at 4 K is observed, in plying that the in-plane e ective supercarrier m ass m a_{b}

is oxygen-isotope dependent with $\mbox{ m}_{\mbox{ ab}} = m_{\mbox{ ab}} = 5.5\,(1.4)\%$.

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One of the fundamental questions concerning the physics of cuprate high-tem perature superconductors (HTSC) is whether the electron-phonon interaction plays an essential role in these systems or not. The high values of the superconducting transition tem perature T_c and the observation of only a tiny oxygen-isotope shift of T_c in optimally doped HTSC (see, e.g. [1]) were taken as in portant arguments to propose alternative pairing mechanism sofpurely electronic origin. The conventional phonon-m ediated theory of superconductivity is based on the Migdaladiabatic approximation in which the e ective supercarrier m ass m is independent of the m ass M of the lattice atom s. How ever, if the interaction between the carriers and the lattice is strong enough, the M igdal adiabatic approxim ation breaks down and m depends on M (see, e.g. [2]). The ideal experiment to explore a possible coupling of the supercarriers to the lattice is an isotope e ect study of the magnetic eld penetration depth. For HTSC, which are superconductors in the clean lim it, the in-plane penetration depth _{ab} obeys the relation:

$$1 = \frac{2}{ab} / n_s = m_{ab}; \qquad (1)$$

where ns is the superconducting charge carrier density and m_{ab} is the in-plane e ective mass of the charge carriers. Note that there is no such simple relation for T_c. Since n_s was found to be predom inantly isotope independent [3, 4, 5, 6, 7, 8, 9], isotope effect experiments on the penetration depth turned out to be a unique tool to investigate unconventional lattice e ects in HTSC. Previous oxygen-isotope e ect studies of the penetration depth in YBa₂Cu₃O₇ **[3]**, La_{2 x} Sr_xCuO₄ [4, 5, 6], Bi_{4:6}Pb_{0:4}Sr₂Ca₂Cu₃O₁₀₊ [7] and $Y_{1 x} Pr_{x} Ba_{2} Cu_{3} O_{7}$ [9] showed indeed a pronounced oxygen isotope dependence of the supercarrier mass. In all these experiments, however, the penetra-

tion depth was determ ined indirectly from magnetization m easurements [3], the M eissner fraction [4, 5], m agnetic torque [6], and muon-spin rotation (SR) experiments [9]. The expression "indirectly" means that all these techniques require a model to extract the absolute value of the penetration depth . In contrast, m easurem ents of the exponential eld decay (B (z) = $B_0 \exp(z=)$) in the M eissner state allow to determ ine in a direct way. Recently, such a direct m easurem ent of the in-plane m agnetic penetration depth $_{ab}$ in a thin YB a_2 C u_3 O $_7$ lm was performed [10] at the Paul Scherrer Institute (PSI, Switzerland) by using the novel low -energy SR (LE SR) technique [11]. In this experim ent the muon im plantation depth was controlled by the variation of the incoming muon energy and the magnitude of the eld was monitored by the muon spin precession frequency, alike in standard SR.

In this Letter, we report on the oxygen-isotope $({}^{16}O/{}^{18}O)$ e ect (O E) on the in-plane magnetic eld penetration depth in a high-quality YBa₂Cu₃O₇ Im near optim al doping measured directly by LE SR. The experiments revealed that in the M eissner state the magnetic eld B (z) in the ${}^{16}O$ substituted sam ple decreases strongerwith distance z than in the ${}^{18}O$ substituted sam – ple, clearly demonstrating that 16 ab < 18 ab.

The sam ples used for the LE SR experiments were high quality Y Ba₂Cu₃O₇ In swith an area of 2x3 cm² and a thickness of 600 nm supplied by Theva [12]. The In swere grown by thermal coevaporation of the constituents onto a single-crystal barium titanate substrate. The oxygen-isotope exchange was performed by annealing the sam ples in ¹⁸O₂ gas. In order to ensure that the ¹⁶O and ¹⁸O substituted sam ples are subject of the sam e therm al history, the annealing (in ¹⁶O₂ and ¹⁸O₂) was performed simultaneously. The exchange process was carried out at 600°C during 25 h, followed by slow cooling (20°C/h) in order to oxidize them completely. The fraction of the 18 O content in the $\,$ m was estimated to be 95%, corresponding to the 18 O content in the initial gas used for the annealing process. The oxygen content (7-) and the quality of the $\,$ m s were estimated from 1m T eld-cooled (FC) SQUID magnetization measurements. The observed $T_{\rm c}$ onsets are $^{16}T_{\rm c}=$ 89:3(1) K

and $^{18}T_{\rm c}$ = 89:1 (1) K. The transition widths are ' 0.9 K for both samples. A comparison of the $T_{\rm c}$'s with the known experimental $T_{\rm c}$ vs curves for 16 O and 18 O substituted YBa₂Cu₃O₇ [13] yields = 0:150 (5) for both lm s. W hile indicates that the samples are slightly underdoped the narrow transition shows that the oxygen distribution over the lm s is quite hom ogeneous. The results of the O IE on $T_{\rm c}$ are sum marized in Table I.

TABLE I: Sum mary of the O \mathbb{E} results for YBa₂Cu₃O₇ extracted from the experimental data (see text for an explanation).

M ethod	Sample	¹⁶ T _c	¹⁸ T _c	$T_{c}=T_{c}$	_{ab} = _{ab}	m _{ab} =m _{ab}
		(K)	(K)	(응)	(%)	(%)
LE SR	Thin Im	89.3(1)	89.1(1)	-0,22 (16)	2.8(7)	5.5(1.4)
M agnetization	F ine pow der	91.66(3)	91.42(3)	-0,26(5)	3.0(1.1)	6.0(2.2)
		91.71(3) ^a	91.45(1) ^b	-0.28 (5)	2.4(1.0)	4.8(2.0)

^a results for the back-exchange (18 O ! 16 O) sam ple

The transverse-eld LE SR experiments were performed on the E3 muon beam line at PSI. A weak external magnetic eld $B_0 = 92$ mT was applied parallel to the sample surface after the sample was cooled in zero magnetic eld from a temperature above T_c to 4 K. Spin-polarized muons were implanted at a depth ranging from 20-150 nm beneath the surface of the lm by varying the energy of the incident muons from 3 to 30 keV. For each implantation energy a time-di erential

SR spectrum was measured. The muon implantation depth prolen(z) for the given implantation energy was calculated using a M onte-C arlo code TR \mathbb{M} SP [14]. The reliability of the calculated n(z) was crosschecked by previous LE SR experiments on thin metal layers [15].

The experimental data were analyzed in the following way. For each implantation energy the average value of the magnetic eld B and correspondent average value of the stopping distance z were extracted. The value of B was taken from the t of the time evolution of the muon-spin polarization spectrum by using the Gaussian relaxation function:

$$a(t) = a_0 \exp(2t^2 = 2) \cos(Bt +);$$
 (2)

where a_0 is the initial asymmetry, is the Gaussian relaxation rate, and = 2 135M Hz/T is the gyrom agnetic ratio of the muon. Note that at our level of statistics (5 10^5 events per spectrum) the t of experimental data with Eq. (2) satisfies the ² criterium. The value of z was taken as the rst moment of the emulated n (z) distribution. Results of this analysis for the ¹⁶O and ¹⁸O substituted YBa₂Cu₃O₇ In s are shown in Fig.1. The data points for the 18 O lm are system atically higher than those for the 16 O lm, showing that 16 $_{ab}$ $<^{18}$ $_{ab}$. The solid lines represent a t to the B data by the function:

$$B(z) = B_0 \frac{\cosh[(t - z) = ab]}{\cosh(t = ab)};$$
 (3)

This is the form of the classical exponential eld decay in the M eissner state B (z) = $B_0 \exp(z = ab)$, m odied for a lm with thickness 2t with ux penetrating from both sides. The value of z was corrected by $z_0 = 8 \text{ nm}$, corresponding to a "dead layer", which mainly arises from the surface roughness of the lm [10]. Fits with Eq. (3) to the extracted ${}^{16}B$ (z) and ${}^{18}B$ (z) yield 16 _{ab} (4K) = 151:85(75) nm and 18 _{ab} (4K) = 155:82(68) nm. Taking into account a ¹⁸O content of 95%, the relative shift was found to be ab⁼ ab = $\binom{18}{ab} = \binom{16}{ab} = 2.8 (7)$ % at 4 K. This value is consistent with previous results for optim ally doped $YBa_2Cu_3O_7$ [3] and $Bi_{1:6}Pb_{0:4}Sr_2Ca_2Cu_3O_{10+}$ [7] obtained from indirect magnetization measurements. Here we would like to mention two important points: (i) The good agreem ent between the experimental points and theoretical curves (Eq. (3)) indicates that the lm s are hom ogenous over the whole thickness. (ii) ab obtained from LE SR is model independent. It is extracted from the measured eld pro le in the Meissner state using only one t parameter _{ab}.

We also performed additional O \mathbb{E} experiments on ab based on measurements of the Meissner fraction in ne YBa₂Cu₃O₇ powder. The powder samples were

^b results for the back-exchange (¹⁶0! ¹⁸0) sam ple

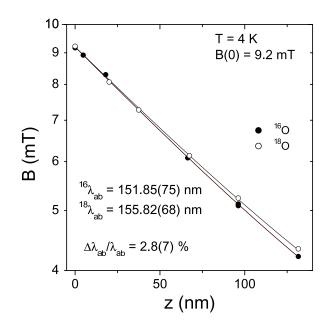


FIG.1: M agnetic eld penetration pro les B (z) for a 16 O substituted (closed symbols) and a 18 O substituted (open symbols) Y Ba₂Cu₃O₇ Im measured in the M eissner state at 4 K and an external eld of 9.2 m T, applied parallel to the surface of the Im. The data are shown for implantation energies 3, 6, 10, 16, 22, and 29 keV starting from the surface of the sample. Solid curves are best ts by Eq.(3).

ground for about 60 m in and then passed through a 10 m sieve. The oxygen exchange procedure was analogous to the one described above for the thin lm sam ples. The ¹⁸O content in the sample, as determined from the change of the sample weight after the isotope exchange, was found to be 89(2)%. The value of the Meissner fraction f was calculated from 1 mT FC SQUD magnetization measurements. The absence of weak links between grains was con med by the linear magnetic eld dependence of the FC magnetization measured at 5 K in 0.5 m T, 1 m T, and 1.5 m T. The tem perature dependence of the magnetic eld penetration depth e (powder average) was calculated from f under the assumption that the sample grains are spherical [16]. The in-plane penetration depth _{ab} (T) (Fig. 2) was determ ined from the measured $_{\rm e}$ (T) using the relation $_{\rm e}$ = 1:31 $_{\rm ab}$ which holds for highly anisotropic superconductors ($_{c}=_{ab} > 5$) [17]. Taking into account a ¹⁸O content of 89%, the relative shift at 4 K was found to ab = ab = 3:0(1:1)% in a good agreem ent with the be LE SR data (see Table I). In order to substantiate the intrinsic character of the observed O IE on ab, we perform ed a back exchange experim ent. For this purpose the $^{16}{\rm O}$ sample was annealed in $^{18}{\rm O}_2$ gas ($^{16}{\rm O}$! $^{18}{\rm O}$) and the 18 O sample in 16 O₂ gas (18 O! 16 O). The annealing procedure was analogous to the one described above for the thin lm samples. The results of the back exchange experim ents are also shown in Fig. 2 (cross symbols). All the results of the O ${\rm I\!E}\,$ on ${\rm T_c}$ and $~_{ab}$ are sum m arized in Table I.

A coording to Eq. (1) the O \mathbbm{E} on $_{ab}$ is due to a shift in n_s and/orm $_{ab}$:

$$\frac{ab}{ab} = \frac{1}{2} \frac{m_{ab}}{m_{ab}} - \frac{1}{2} \frac{n_{s}}{n_{s}} :$$
 (4)

Previous OIE studies in HTSC's [3, 4, 5, 6, 7, 8, 9] showed a pronounced O IE on m ab with negligible O IE on ns. In the present work we provide further evidence of this scenario from measurements of the nuclear quadrupole resonance (NQR) frequency $(_{0})$ of the plane $\binom{p1}{0}$ and the chain $\binom{ch}{0}$ ^{63}Cu in ^{16}O and ^{18}O substituted $Y \tilde{B} a_2 C u_3 O_7$ pow der sam ples. It is known [18, 19] that in HTSC $_Q^{p1}$ and $_Q^{ch}$ are very sensitive to changes in the density of mobile carriers n in the superconducting CuO₂ planes (n^{p1}) and CuO chains (n^{ch}). Both 0^{p1} and ch increase with doped hole concentration roughly 20 M H z per one doped hole per C u atom [20]. The N Q R m easurements of 63 Cu at 94 K show that within 5 kHz error bar lim its the plane copper and the chain copper NQR frequencies are the same in $^{16}\mathrm{O}$ and $^{18}\mathrm{O}$ substituted YBa₂Cu₃O₇ powder sam ples (see Table II). This im plies that by the oxygen substitution n^{pl} and n^{ch} change for less than 3 10^4 hole per Cu atom . In optimally doped $YBa_2Cu_3O_7$ one has two plane and one chain Cu atom in the unit cell. From the NQR measurements we can thus conclude that the change of the hole num ber per unit cell is less than 3 $3 10^4$ ' 10^3 hole. Since in optim ally doped $Y B a_2 C u_3 O_7$ there is approxim ately one doped hole per unit cell, the relative change of hole density n=n at the oxygen exchange must be less than 10 3 . The NQR results are summarized in Table II. For it was shown [21] that n_s $YBa_2Cu_3O_7$ n at T < 70 K.Based on this observation we thus can conclude $n_s = n_s j < 0.05\%$ in Eq.(4). Consequently, that 1=2 the main contribution to the O IE on ab has to come from the isotope dependence of the in-plane charge carrierm assm_{ab}, so that ab = ab' (m ab = mab)/2.W ith ab = ab = 2.8(7)% we obtain m ab = mab = 5.5(1.4)% at 4 K (see Table I). This result is remarkable in spite of the fact that the observed O IE on T_c in optim ally doped $YBa_2Cu_3O_7$ is rather sm all ($T_c=T_c = 0.26(5)$ %, see Table I).

Note that such an isotope e ect on m_{ab} is not expected for a conventional weak-coupling phonon-m ediated BCS superconductor. In fact in HTSC the charge carriers are strongly coupled to optical phonons, as dem onstrated by m easurem ents of the static and high-frequency dielectric constants [22], photoem ission [23] and tunnelling [24] experim ents. Strong interaction between the charge carriers and the lattice ions leads to a break down of the adiabatic M igdal approximation [2], and consequently the e ective supercarrier mass m depends on the mass of the lattice atom s. To our know ledge there are just a few

TABLE II: Results of plane and chain ${}^{63}CuNQR$ in ${}^{16}O$ and ${}^{18}O$ substituted YBa₂Cu₃O₇ powder sam ples at 94 K (see text for an explanation).

	¹⁶ 0		1		
	Q	Linewidth	Q	Linewidth	
	(MHz)	(KHz)	(M H z)	(KHz)	(응)
P lanes	31.580 (5)	336 (10)	31.580 (5)	340 (10)	0.00(2)
Chains	22.050 (5)	161 (5)	22.050 (5)	161 (5)	0.00(3)

theoretical models which predict an O \mathbbm{E} on the electric carrier mass m (see e.g. Refs. 2, 25, 26, 27).

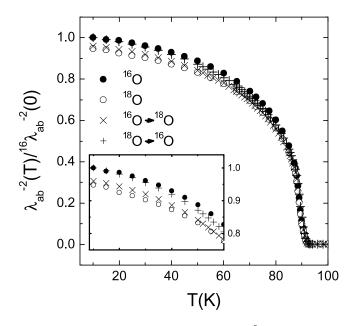


FIG. 2: Temperature dependence of $_{ab}^{2}$ normalized by $_{ab}^{16}$ (0) for $_{ab}^{16}$ O and 18 O substituted YBa₂Cu₃O₇ nepow-der sam ples as obtained from low - eld SQUID magnetization m easurem ents. The inset shows the low-temperature region between 10 K and 60 K. The reproducibility of the oxygen exchange procedure was checked by the backexchange (crosses).

In conclusion, we used LE SR to measure directly the oxygen isotope $({}^{16}O/{}^{18}O)$ e ect on the in-plane magnetic eld penetration depth ab in optimally doped $\mbox{lm}\mbox{s. The O IE}$ on $\mbox{}_{\mbox{ab}}$ at 4 K was found $YBa_2Cu_3O_7$ to be ab = ab = 2:8(7)%. The intrinsic character of the O ${\rm I\!E}\,$ on $\,_{\rm ab}\,$ was con rm ed by back exchange experiments on ne powders with low - eld SQUID maqnetization m easurem ents. It is concluded that the O IE arises mainly from the isotope dependence of the in-plane charge carrier m ass m_{ab} with m_{ab}=m_{ab} = 5:5(1:4)% at 4 K. This nding implies that even in optimally doped cuprate superconductors for which only a small isotope e ect on T_c is observed, the supercarriers are strongly coupled to the lattice.

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